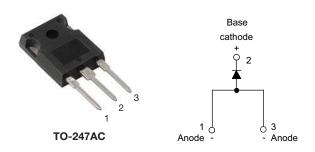


## VS-80APF1.PbF Series, VS-80APF1.-M3 Series

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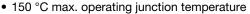
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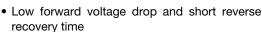
## Fast Soft Recovery Rectifier Diode, 80 A

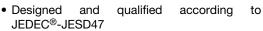


PRODUCT SUMMARY						
Package	TO-247AC					
I <sub>F(AV)</sub>	80 A					
$V_{R}$	1000 V, 1200 V					
V <sub>F</sub> at I <sub>F</sub>	1.35 V					
I <sub>FSM</sub>	1250 A					
t <sub>rr</sub>	90 ns					
T <sub>J</sub> max.	150 °C					
Diode variation	Single die					
Snap factor	0.5					

#### **FEATURES**







Material categorization:
For definitions of compliance please see <a href="https://www.vishay.com/doc?99912">www.vishay.com/doc?99912</a>





ROHS COMPLIANT HALOGEN FREE

#### **APPLICATIONS**

These devices are intended for use in output rectification and freewheeling in inverters, choppers and converters as well as in input rectification where severe restrictions on conducted EMI should be met.

#### **DESCRIPTION**

The VS-80APF1... soft recovery rectifier series has been optimized for combined short reverse recovery time and low forward voltage drop.

The glass passivation ensures stable reliable operation in the most severe temperature and power cycling conditions.

MAJOR RATINGS AND CHARACTERISTICS									
SYMBOL	TEST CONDITIONS	VALUES	UNITS						
V <sub>RRM</sub>		1000/1200	V						
I <sub>F(AV)</sub>	Sinusoidal waveform	80	۸						
I <sub>FSM</sub>		1250	Α						
t <sub>rr</sub>	1 A, - 100 A/μs	90	ns						
V <sub>F</sub>	40 A, T <sub>J</sub> = 25 °C	1.2	V						
TJ		-40 to 150	°C						

VOLTAGE RATINGS									
PART NUMBER	V <sub>RRM</sub> , MAXIMUM PEAK REVERSE VOLTAGE V	V <sub>RSM</sub> , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I <sub>RRM</sub> AT 150 °C mA						
VS-80APF10PbF, VS-80APF10-M3	1000	1100	15						
VS-80APF12PbF, VS-80APF12-M3	1200	1300	13						

# VS-80APF1.PbF Series, VS-80APF1.-M3 Series

ABSOLUTE MAXIMUM RATINGS								
PARAMETER SYMBOL TEST CONDITIONS VALUES								
Maximum average forward current	I <sub>F(AV)</sub>	T <sub>C</sub> = 92 °C, 180° conduction half sine wave	80					
Maximum peak one cycle		10 ms sine pulse, rated V <sub>RRM</sub> applied	1100	Α				
non-repetitive surge current	IFSM	10 ms sine pulse, no voltage reapplied	1250					
Maximum I <sup>2</sup> t for fusing	I <sup>2</sup> t	10 ms sine pulse, rated V <sub>RRM</sub> applied	5000	A <sup>2</sup> s				
Maximum i-t for fusing	1-1	10 ms sine pulse, no voltage reapplied	7000	A-S				
Maximum I <sup>2</sup> √t for fusing	I²√t	t = 0.1 ms to 10 ms, no voltage reapplied	70 000	A²√s				

ELECTRICAL SPECIFICATIONS									
PARAMETER	SYMBOL	TEST CO	VALUES	UNITS					
Maximum forward voltage drop	$V_{FM}$	80 A, T <sub>J</sub> = 25 °C	1.35	V					
Forward slope resistance	r <sub>t</sub>	T 150 °C	4.03	mΩ					
Threshold voltage	V <sub>F(TO)</sub>	T <sub>J</sub> = 150 °C	0.87	V					
Maximum reverse leakage current	,	T <sub>J</sub> = 25 °C	V <sub>B</sub> = Rated V <sub>BBM</sub>	0.1	mA				
iviaximum reverse leakage current	I <sub>RM</sub>	T <sub>J</sub> = 150 °C	V <sub>R</sub> = nateu V <sub>RRM</sub>	15	IIIA				

RECOVERY CHARACTERISTICS								
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	· •			
Reverse recovery time	t <sub>rr</sub>	Is at 80 Ank	480	ns	I <sub>FM</sub> +			
Reverse recovery current	I <sub>rr</sub>	I <sub>F</sub> at 80 A <sub>pk</sub> 25 A/μs	7.1	Α				
Reverse recovery charge	Q <sub>rr</sub>	25 °C	2.1	μC	dir/ Q <sub>rr</sub>			
Snap factor	S		0.5		I <sub>RM(REC)</sub>			

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Maximum junction and stemperature range	storage	T <sub>J</sub> , T <sub>Stg</sub>		-40 to 150	°C			
Maximum thermal resist junction to case	ance,	R <sub>thJC</sub>	DC operation	0.35				
Maximum thermal resistance, junction to ambient		R <sub>thJA</sub>		40	°C/W			
Typical thermal resistance, case to heatsink		R <sub>thCS</sub>	Mounting surface, smooth and greased	0.2				
Approximate weight				6	g			
Approximate weight				0.21	oz.			
Maunting toward	minimum			6 (5)	kgf · cm			
Mounting torque -	maximum			12 (10)	(lbf ⋅ in)			
Marking davios			Consideration TO 247AC	80APF10				
Marking device			Case style TO-247AC	80APF12				



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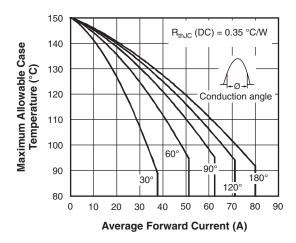


Fig. 1 - Current Rating Characteristics

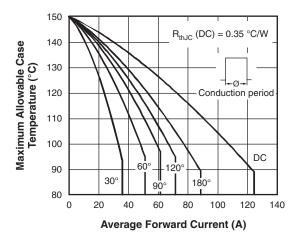


Fig. 2 - Current Rating Characteristics

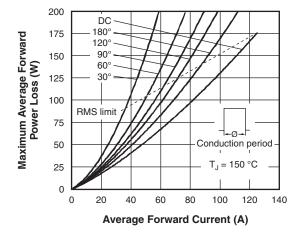


Fig. 3 - Forward Power Loss Characteristics

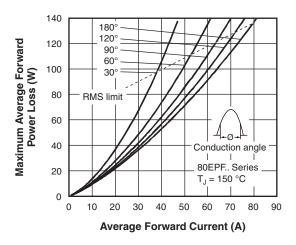


Fig. 4 - Forward Power Loss Characteristics

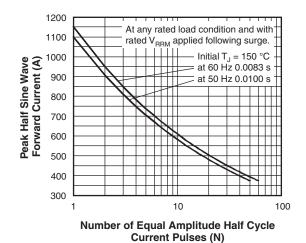


Fig. 5 - Maximum Non-Repetitive Surge Current

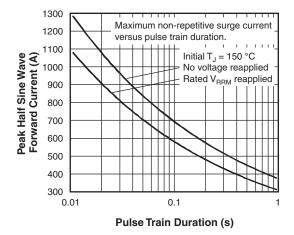


Fig. 6 - Maximum Non-Repetitive Surge Current

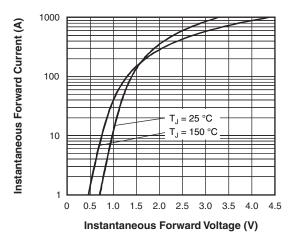


Fig. 7 - Forward Voltage Drop Characteristics

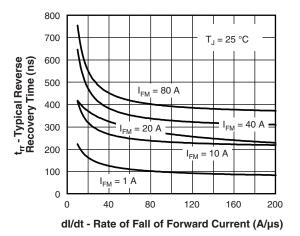


Fig. 8 - Recovery Time Characteristics, T<sub>J</sub> = 25 °C

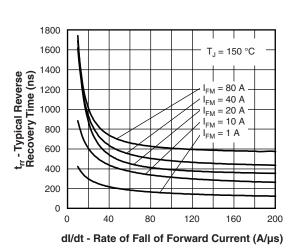
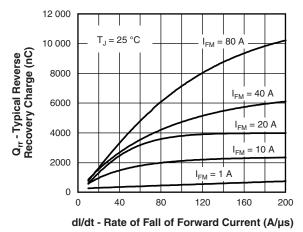
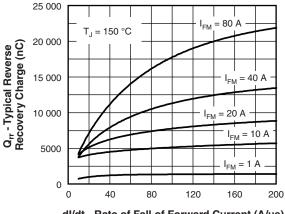


Fig. 9 - Recovery Time Characteristics, T<sub>J</sub> = 150 °C







dl/dt - Rate of Fall of Forward Current (A/µs)

Fig. 11 - Recovery Charge Characteristics, T<sub>J</sub> = 150 °C



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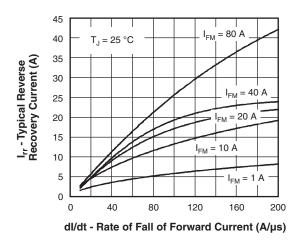


Fig. 12 - Recovery Current Characteristics, T<sub>J</sub> = 25 °C

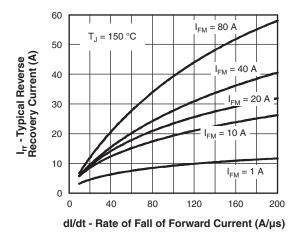


Fig. 13 - Recovery Current Characteristics, T<sub>J</sub> = 150 °C

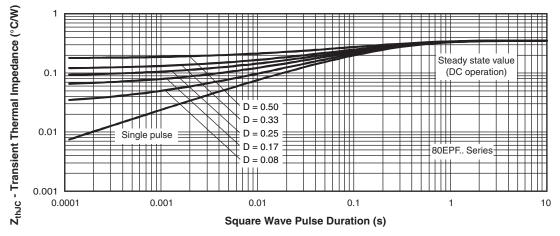


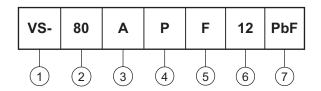
Fig. 14 - Thermal Impedance ZthJC Characteristics

## VS-80APF1.PbF Series, VS-80APF1.-M3 Series

Vishay Semiconductors

#### **ORDERING INFORMATION TABLE**

**Device code** 



Vishay Semiconductors product

2 - Current rating (80 = 80 A)

3 - Circuit configuration:

A = Single diode, 3 pins

4 - Package:

P = TO-247AC

5 - Type of silicon:

F = Fast recovery

10 = 1000 V 12 = 1200 V

7 - Environmental digit:

• PbF = Lead (Pb)-free and RoHS compliant

• -M3 = Halogen-free, RoHS compliant and terminations lead (Pb)-free

ORDERING INFORMATION (Example)									
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION						
VS-80APF10PbF	25	500	Antistatic plastic tubes						
VS-80APF10-M3	25	500	Antistatic plastic tubes						
VS-80APF12PbF	25	500	Antistatic plastic tubes						
VS-80APF12-M3	25	500	Antistatic plastic tubes						

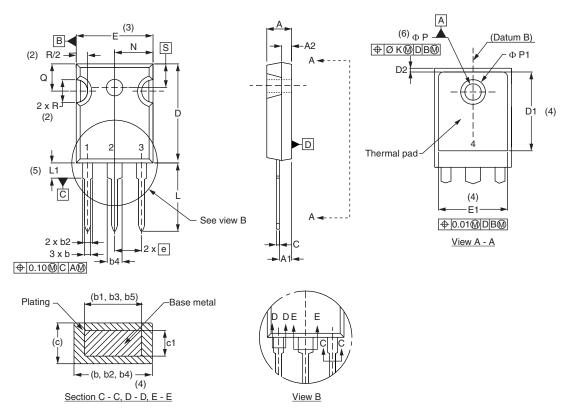
LINKS TO RELATED DOCUMENTS							
Dimensions <u>www.vishay.com/doc?95542</u>							
Dout moulting information	TO-247AC PbF	www.vishay.com/doc?95226					
Part marking information	TO-247AC -M3	www.vishay.com/doc?95007					



Vishay Semiconductors

### TO-247 - 50 mils L/F

#### **DIMENSIONS** in millimeters and inches



SYMBOL	MILLIN	IETERS	INC	HES	NOTES	SYMBOL	MILLIM	IETERS	INC	HES	NOTES	
STIMBOL	MIN.	MAX.	MIN.	MAX.	NOTES	NOTES	STWIBOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.65	5.31	0.183	0.209			D2	0.51	1.35	0.020	0.053	
A1	2.21	2.59	0.087	0.102			E	15.29	15.87	0.602	0.625	3
A2	1.17	1.37	0.046	0.054			E1	13.46	=.	0.53	-	
b	0.99	1.40	0.039	0.055			е	5.46	BSC	0.215	BSC	
b1	0.99	1.35	0.039	0.053			ØK	0.2	254	0.0	10	
b2	1.65	2.39	0.065	0.094			L	14.20	16.10	0.559	0.634	
b3	1.65	2.34	0.065	0.092			L1	3.71	4.29	0.146	0.169	
b4	2.59	3.43	0.102	0.135			N	7.62	BSC	0	.3	
b5	2.59	3.38	0.102	0.133			ØΡ	3.56	3.66	0.14	0.144	
С	0.38	0.89	0.015	0.035			Ø P1	ı	7.39	-	0.291	
c1	0.38	0.84	0.015	0.033			Q	5.31	5.69	0.209	0.224	
D	19.71	20.70	0.776	0.815	3		R	4.52	5.49	0.178	0.216	
D1	13.08	-	0.515	-	4		S	5.51	BSC	0.217	BSC	

#### **Notes**

- (1) Dimensioning and tolerancing per ASME Y14.5M-1994
- (2) Contour of slot optional
- (3) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Thermal pad contour optional with dimensions D1 and E1
- (5) Lead finish uncontrolled in L1
- (6) Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")
- $^{(7)}$  Outline conforms to JEDEC® outline TO-247 with exception of dimension c and Q



### **Legal Disclaimer Notice**

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Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as RoHS-Compliant fulfill the definitions and restrictions defined under Directive 2011/65/EU of The European Parliament and of the Council of June 8, 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment (EEE) - recast, unless otherwise specified as non-compliant.

Please note that some Vishay documentation may still make reference to RoHS Directive 2002/95/EC. We confirm that all the products identified as being compliant to Directive 2002/95/EC conform to Directive 2011/65/EU.

Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as Halogen-Free follow Halogen-Free requirements as per JEDEC JS709A standards. Please note that some Vishay documentation may still make reference to the IEC 61249-2-21 definition. We confirm that all the products identified as being compliant to IEC 61249-2-21 conform to JEDEC JS709A standards.

Revision: 02-Oct-12 Document Number: 91000

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Vishay:

VS-80APF10PBF VS-80APF12PBF